

Vishay Siliconix

Complementary 30 V (D-S) MOSFET

PRODUCT SUMMARY						
	V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
N-Channel	30	0.085 at V _{GS} = 10 V	± 3.9			
		0.143 at V _{GS} = 4.5 V	± 3.0			
P-Channel	- 30	0.165 at V _{GS} = - 10 V	± 2.8			
		0.290 at V _{GS} = - 4.5 V	± 2.1			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC



FREE

V

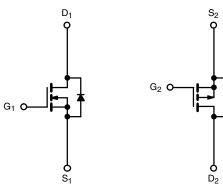
А

W

°C

1206-8 ChipFET® Marking Code FA XX Lot Traceability and Date Code Part # Code **Bottom View**

Ordering Information: Si5504DC-T1-E3 (Lead (Pb)-free)



P-Channel MOSFET

N-Channel MOSFET Si5504DC-T1-GE3 (Lead (Pb)-free and Halogen-free) ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted N-Channel **P-Channel** Symbol Parameter **Steady State Steady State** Unit 5 s 5 s **Drain-Source Voltage** V_{DS} 30 - 30 Gate-Source Voltage V_{GS} +20 $T_A = 2\overline{5 \ ^{\circ}C}$ ± 2.9 ± 3.9 ± 2.8 ± 2.1 Continuous Drain Current (T_J = 150 °C)^a I_D T_A = 85 °C ± 2.8 ± 2.0 ± 1.5 ± 2.1 **Pulsed Drain Current** IDM ± 10 Is 1.8 0.9 - 1.8 - 0.9 Continuous Source Current (Diode Conduction)^a T_A = 25 °C 2.1 2.1 1.1 1.1 Maximum Power Dissipation^a P_D T_A = 85 °C 1.1 0.6 1.1 0.6 Operating Junction and Storage Temperature Range T_J, T_{stq} - 55 to 150 260 Soldering Recommendations (Peak Temperature)^{b, c}

THERMAL RESISTANCE RATINGS									
Parameter		Symbol	Typical	Maximum	Unit				
Maximum har dian to Archiveta	t ≤ 5 s	R _{thJA}	50	60					
Maximum Junction-to-Ambient ^a	Steady State		90	110	°C/W				
Maximum Junction-to-Foot (Drain) Steady State		R _{thJF}	30	40					

Notes:

a. Surface mounted on 1" x 1" FR4 board.

b. See reliability manual for profile. The ChipFET/PowerPAK is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static	•	•						
Cata Thrashold Veltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ N-Cl		1.0			V	
Gate Threshold Voltage		$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	P-Ch	- 1.0			V	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	N-Ch			± 100	nA	
			P-Ch			± 100		
	I _{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$	N-Ch	-Ch		1	- μΑ	
Zero Gate Voltage Drain Current		$V_{DS} = -24 V, V_{GS} = 0 V$ P-Ch				- 1		
		V_{DS} = 24 V, V_{GS} = 0 V, T_{J} = 85 °C	N-Ch	N-Ch		5		
		$V_{DS} = -24$ V, $V_{GS} = 0$ V, $T_{J} = 85$ °C	P-Ch			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5$ V, $V_{GS} = 10$ V	N-Ch	10			А	
		$V_{DS} \le$ - 5 V, V_{GS} = - 10 V	P-Ch	- 10			A	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.9 \text{ A}$	N-Ch		0.072	0.085		
		V _{GS} = - 10 V, I _D = - 2.1 A	P-Ch		0.137	0.165		
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 2.2 \text{ A}$	N-Ch		0.120	0.143	Ω	
		V _{GS} = - 4.5 V, I _D = - 1.6 A	P-Ch		0.240	0.290		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 2.9 A	N-Ch		6			
		V _{DS} = - 15 V, I _D = - 2.1 A	P-Ch		3		S	
	V_{SD}	I _S = 0.9 A, V _{GS} = 0 V	N-Ch		0.8	1.2	v	
Diode Forward Voltage ^a		I _S = - 0.9 A, V _{GS} = 0 V	P-Ch		- 0.8	- 1.2		
Dynamic ^b		· · · · · ·						
Total Cata Charge	Qg	N-Channel $V_{DS} = 15 V, V_{GS} = 10 V, I_D = 2.9 A$	N-Ch		5	7.5	nC	
Total Gate Charge			P-Ch		5.5	6.6		
Gate-Source Charge	Q _{gs}	$v_{\rm DS} = 10 v, v_{\rm GS} = 10 v, 10 = 2.9 A$	N-Ch		0.8			
g-		P-Channel	P-Ch		1.2			
Gate-Drain Charge	Q _{gd}	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -2.1 \text{ A}$	N-Ch		1.0			
			P-Ch N-Ch		0.9 7	11		
Turn-On Delay Time	t _{d(on)}	N-Channel	P-Ch		8	12		
	t _r	V_{DD} = 15 V, R_L = 15 Ω	N-Ch		12	12	ns	
Rise Time		$I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω	P-Ch		11	18		
Ture Off Delay Time	t _{d(off)}	P-Channel	N-Ch		12	18		
Turn-Off Delay Time		$V_{DD} = -15 \text{ V}, \text{ R}_{L} = 15 \Omega$	P-Ch		14	21		
Fall Time	t _f	$I_D \cong -1$ A, $V_{GEN} = -10$ V, $R_g = 6 \Omega$	N-Ch		7	11		
		, , , , , , , , , , , , , , , , , , ,	P-Ch		8	12		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 0.9 A, dl/dt = 100 A/μs N-Ch			40	80		
		I _F = - 0.9 A, dl/dt = 100 A/µs	P-Ch		40	80		

Notes:

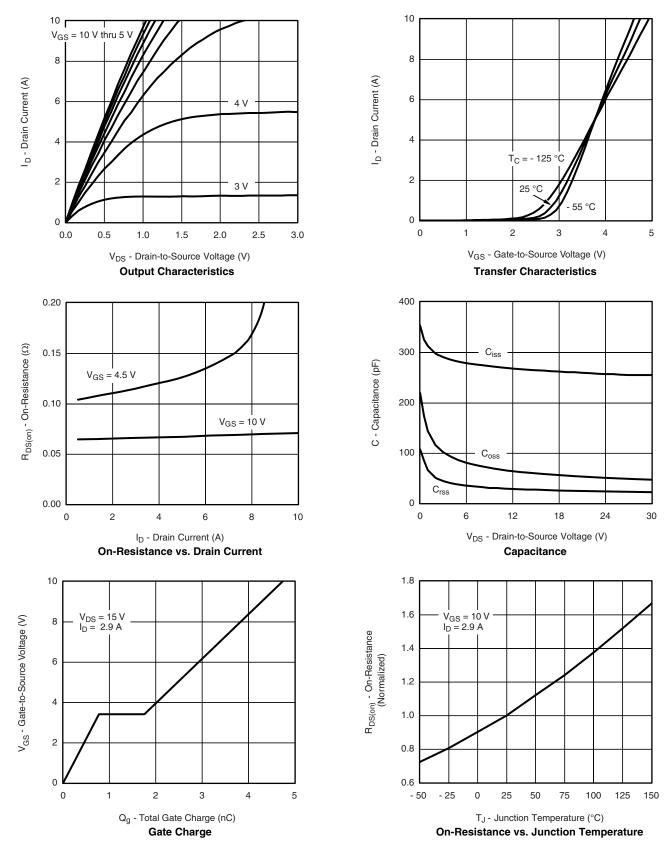
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



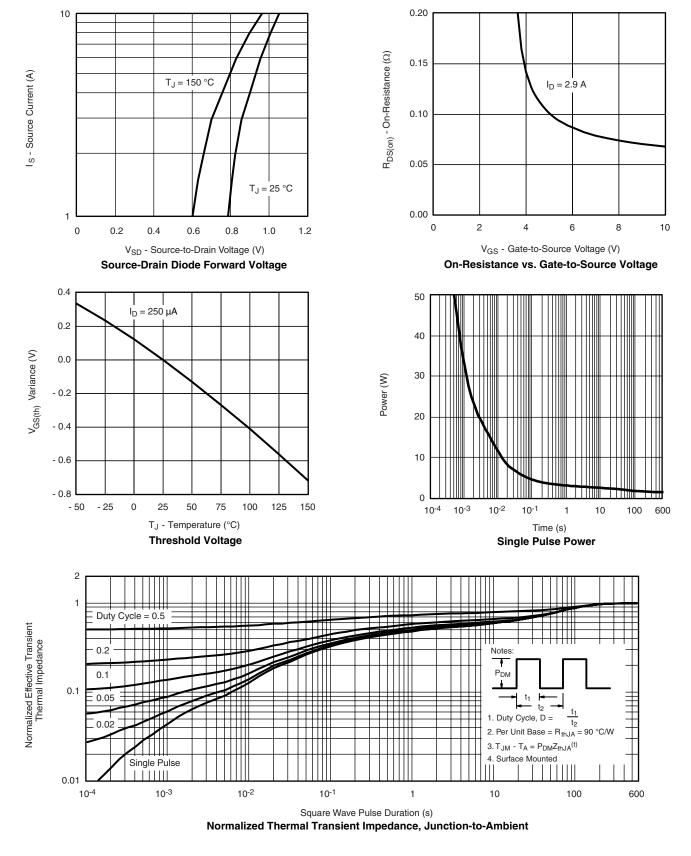
N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Document Number: 71056 S10-0547-Rev. C, 08-Mar-10

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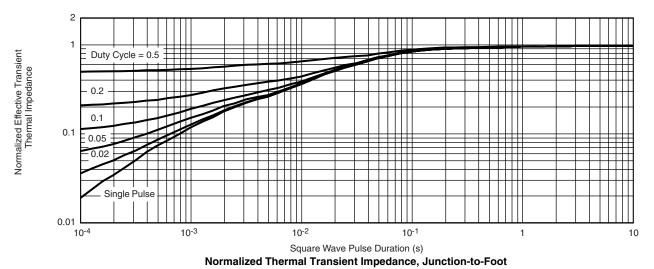


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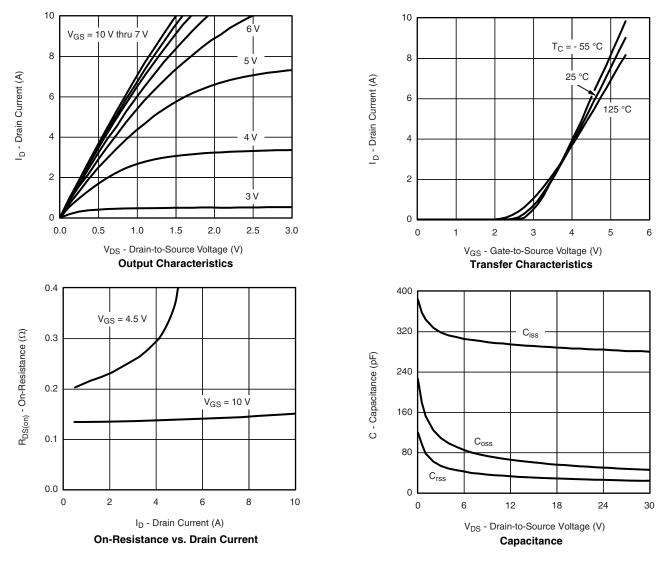


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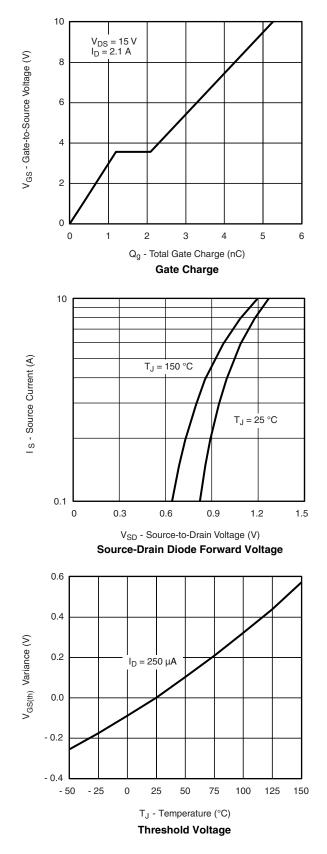


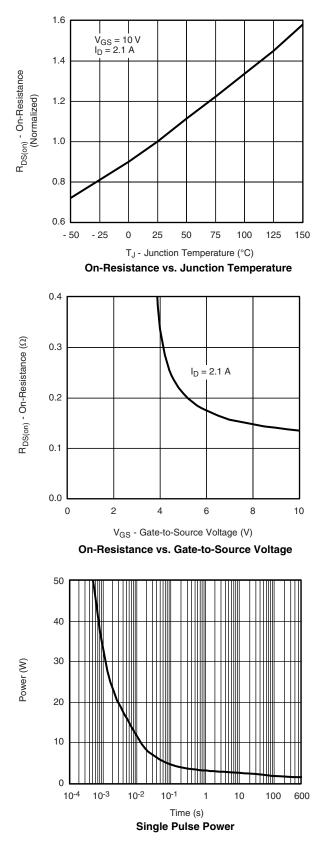
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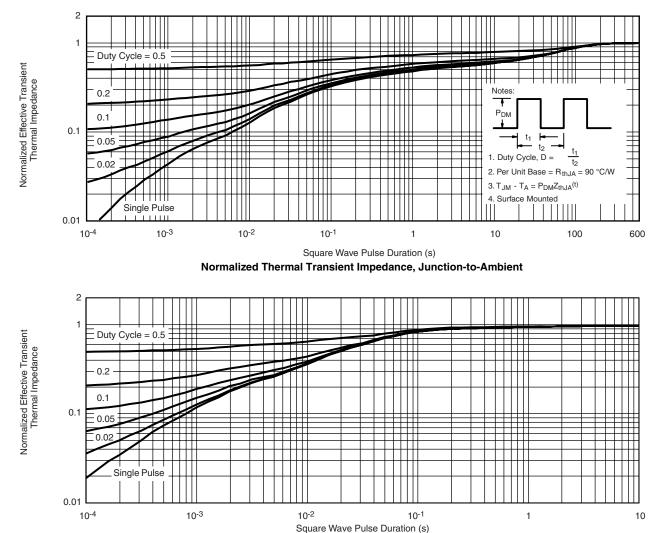




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P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71056.



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